Azette's ducational Supplement -----



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Educational Consultant Awatef Ahmed

(10)In the opposite figure, if the current intensity passing through



(1) In the figure, the ratio, $\frac{I_{x}}{I_{z}} = \cdots$ a)_11 b) $\frac{11}{4}$ $d)^{\frac{2}{1}}$ $c)\frac{1}{2}$ The correct answer is a) $\frac{6}{11}$ Because, from ohm's law for closed circuit I = $\frac{V_B}{R+r}$ $I_1 = \frac{v}{10+1} = \frac{v}{11}$, $I_2 = \frac{v}{5+1} = \frac{v}{6} \rightarrow \frac{I_1}{I_2} = \frac{6}{11}$ (2) In the circuit shown in the figure what happens to the voltmeter reading when the (K) is closed a) Increas b) decrease d) decrease to half c) Remains constant The correct answer is: decrease Because $V = V_B - Ir$ (when key of external circuit is closed the electric current intensity increased and that is inversely proportion with potential difference from ohm's law of closed circuit) (3)The equivalent resistance in the following cases : a)When(k) is open is a)2 b)4 c)6 d)8 b)When(k) is closed is . a)2 b)4 c)6 d)8 The correct answer is: a) open 4Ω b) closed 3Ω Because, in case of open circuit $6\Omega//3\Omega$ series $6\Omega//3\Omega R_{gg} = 2 + 2 = 4\Omega$ But, in case of closed circuit $6\Omega//6\Omega$, $R_{gq} = 3\Omega$

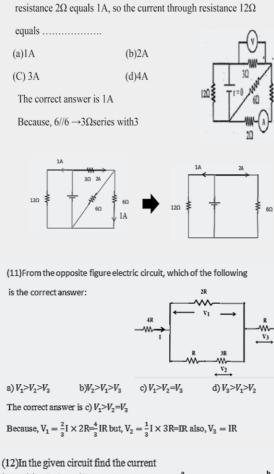
(4)From the opposite diagram R_{eq} =..... 180 a)72Ω b) 6 Ω c) $\frac{54}{11}\Omega$ d) zero Ω The correct answer is 6Ω Because, 18 Ω //9 Ω (6 Ω is cancelled) $R_{eq} = \frac{18\times9}{18+9} = 6\Omega$ (5)By increasing (R⁻) in the shown circuit,

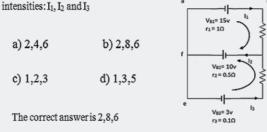
| the reading of | voltmeter | ┎┸╣╒╾╕ |
|----------------|-----------------|--------|
| a) Increase | b) doubled | R |
| c) Decrease | d) remains same | • |

R-

The correct answer is : decreases

Because; if the battery has an internal resistance r Ω

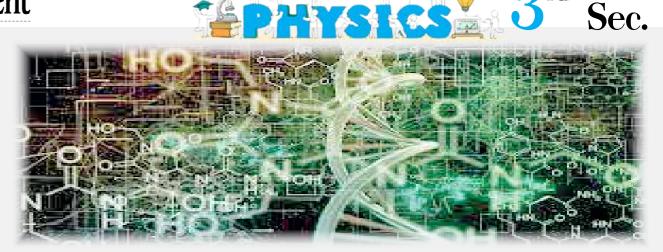




Because, Applying Kirchhoff's first law at point (c): $I_1 + I_3 = I_2 \longrightarrow$ (1). Applying Kirchhoff's second law to the closed path (loop) (a b c f a) $\sum V_{\mu} = \sum IR$ 15 + 10 = (1 + 9.5) |₁ + 0.5 |₂ multiplying x 2 $50 = 21 I_1 + 1 I_2$ (2). Applying Kirchhoff's second law to the closed path (loop) (f c d e f) $\sum V_B = \sum IR.$ $3 + 10 = 0.5 |_2 + (0.1 + 1.4) |_3$ tiplying x 2 26 = l₂ + 3 l₃ → (3).

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From equations (1) and (2),
         50 = 20 (l_2 - l_3) + l_2 = 22 l_2 - 21 l_3 \longrightarrow (4).
Multiplying equation (3) x 7 and adding it to equation (4)
          50 = 22 I_2 + 21 I_3 \longrightarrow (4)
By addition: 232 = 29 I_2
                                   I2 = 8A.
Substituting in equation (2)
        50 = 21 |<sub>1</sub> + 8
       l1=2A
Substituting in equation (1), we find that I_3 = 6A
N.B. All the assigned directions are correct since all current intensities are positive
(13) From the opposite electric circuit shown in figure, answer
The following quest:
                                                20V, r=1 Ω
                                                                  Ι,
                                                                  ) 15V,r=0Ω
                                                   30V, r=2Ω
                                                              5Ω
(a) The intensity of current through each battery are.....
(1) -2.35, -3.82, 1.46
                                                  (2) -5.66, -1.52, 5.33
(3) -3.23, -6.69, 4.34
                                                  (4) -4.69, -8.45, 4.12
(b) The terminal voltage of the battery 30V is.....volts.
(1)12
                       (2)13
                                             (3)14
                                                                    (4)15
(c)The potential difference across the resistor 5 \Omega is ......volts.
                                                                    (4)2.5
(1) 5.2
                      (2)2.7
                                             (3)7.2
The correct answer
(a) (1) -2.35,-3.82, 1.46 (b) (4)15v (C) 7.5v
Because.
 Assume directions of current as shown in figure.
 Applying Kirchhoff's first law at point (e):
     |_1 + |_2 = |_3 \longrightarrow (1).
Applying Kirchhoff's second law to the closed path (loop)
(aecba)
      \sum V_{R} = \sum IR
   20 - 30 = 1 \times I_1 - 2 \times I_2
       -10 = |1 - 2 |2
                                  (2).
Applying Kirchhoff's second law to the closed path (loop) (a e f d b a)
20-15 = 1 x l<sub>1</sub> + 5 x l<sub>3</sub>
         5 = I_1 + 5(I_1 + I_2)
\begin{array}{c} 5 = (1 + 5)_2 \\ 5 = 61_2 + 51_2 \end{array} \longrightarrow (3),
Solving equations (2) and (3), by multiplying equation (2) x 5 and equation (3) x 2
        -50 = 5 |1- 10 |2
        10 = 12 |1 + 10 |2
 Adding the two equ
       - 40 = 17 |<sub>1</sub>
         l1 = -2.35A
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The direction of the current l_1 is opposite to the assumed direction. i.e. The battery 20V is in a state of charging. Substituting in (2), we find that: $l_2 = -3.82$ A i.e. the battery 30 V is in a state of



(14) In a pure Si crystal the concentration of each free electrons or holes is 1.5× 10¹⁰ cm⁻³ if it is doped with 5-valency Arsenic by the concentration 10¹³ cm⁻³ atoms/cm⁻³, then the concentration of both free electrons and holes in the

(a) 10¹³, 2.25× 10⁷ (b) 10¹⁰, 2.55× 10¹²

(c) 10¹², 1.5× 10¹⁰ (d) 10³, 2.25× 10¹⁰

The correct answer is (a) 10^{13} , 2.25×10^{7}

Because. $n = N_{D}^{+} = 10^{13} cm^{-3}$

$$0 = \frac{n_i^2}{N_D^+} = \frac{(1.5 \times 10^{10})^2}{10^{13}} = 2.25 \times 10^7 cm^{-3}$$

(15)If you know that the concentration of free electrons or holes in a pure Ge crystal is 10¹⁵cm⁻³. Antimony is added with concentration 6 × 10¹⁷ cm⁻³ and also boron is added with concentration of 10¹⁷ cm⁻³.

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(Answer the following questions)
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(a)The type of this semiconductor is.

(2) negative (3) neutral (4) -2 Positive

(b) The concentration of free electrons and holes are

 $(1)5 \times 10^{17} cm^{-3}, 2 \times 10^{12} cm^{-3}$ (2) $5 \times 10^{15} cm^{-3}, 2 \times 10^{110} cm^{-3}$

 $(3) 9 \times 10^{15} cm^{-3}, 3 \times 10^{12} cm^{-3}$ $(4) 4 \times 10^{17} cm^{-3}, 3 \times 10^{12} cm^{-3}$

(c) The type and concentration of impurities that must be added to make the semiconductor behave as pure semiconductor is.

(1) 5-valency with concentration $5 \times 10^{17} cm^{-3}$

(2) 3-valency with concentration $5 \times 10^{17} cm^{-3}$

(3) 5-valency with concentration $2 \times 10^{12} cm^{-3}$

(4) 3-valency with concentration $3 \times 10^{17} cm^{-3}$

The correct answer is (a) (2) negative

(b) (1) $5 \times 10^{17} cm^{-3}$, $2 \times 10^{12} cm^{-3}$ (c) (2) 3-valency with concentration $5 \times 10^{17} cm^{-3}$

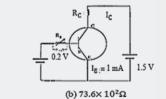
Because.

(a) Since $N_D > N_A$, n-type the semiconductor. (b) $n = N_D - N_A = 6 \times 10^{17} - 10^{17} = 5 \times 10^{17} cm^{-3}$ $=\frac{n_l^2}{(N_D-N_A)}=\frac{(10^{15})^2}{5\times10^{17}}=2\times10^{12}cm^{-3}$ (c) we must add 3-valency impurities as boron or aluminum with concentration $= N_D - N_A = 6 \times 10^{17} - 10^{17} = 5 \times 10^{17} cm^{-3}$.

(16)The concentration of free electrons or holes in pure silicon is $2.4 \times 10^{13} cm^{-3}$

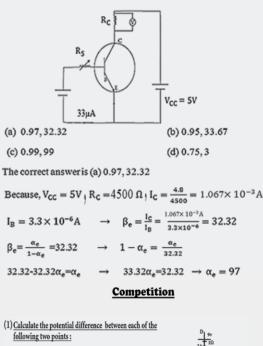
(20) The circuit represents a transistor as invertor gate, if the output Potential $(V_{CE}) = 0.8V$ when the resistance of the base circuit $(R_B = 4000\Omega)$, so the value of the collector circuit resistance $(R_{C}) = \cdots$ approximately.

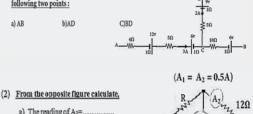
Srd



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(a) 7.36× 10<sup>2</sup>Ω
    (c) 0.736× 10<sup>2</sup>Ω
                                                                                  (d) 7360 \times 10^2 \Omega
    The correct answer is (a) 7.36 \times 10^2 \Omega
      Because.
V_B = 0.2V, V_{CE} = 0.8V, R_B = 4000\Omega
I_{B} = \frac{V_{B}}{R_{B}} = \frac{0.2}{4000} = 5 \times 10^{-5} A
\mathbf{I}_{\mathrm{E}} = \mathbf{I}_{\mathrm{B}} + \mathbf{I}_{\mathrm{C}} \quad \rightarrow \qquad \mathbf{I}_{\mathrm{C}} = \mathbf{I}_{\mathrm{E}} - \mathbf{I}_{\mathrm{B}}
I_{C} = 1 \times 10^{-3} - (5 \times 10^{-5}) = 9.5 \times 10^{-4}
V_{CC} = V_{CE} + I_C R_C \rightarrow 1.5 = 0.8 + 9.5 \times 10^{-4} R_C
R_c = 7.36 \times 10^2 \Omega
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(21) The circuit represents a transistor as an amplifier, if the voltmeter reads 4.8V, and the value of $R_c = 4.5K \Omega$ So, the values of β_e and α_e respectively are ...





a) AE

a) The reading of A₂=...

b) The value of the unknown resistance (R)

| The reading of voltmeter $V = V_B - I(R' + r)$ | |
|--|--|
| (6)If the length of a metal conductor is doubled, and its radius | |
| decrease to half, so the specific resistance is | |
| a) Increased 8 times b) increased 4 times | |
| c) Increased 2 times d) unchanged | |

The correct answer is (d) unchanged

Because, the specific resistance (resistivity) depends only on kind of material

and temperature.

(7)In the shown electric circuit, if the reading of Ammeter (A1)

is 1.2A then the reading of Ammeter (A_2) (a) 0.2 A (b) 0.4A (d) 0.8A (c) 0.6A The correct answer is :(d) 0.8A Because, I=1.2A, $I_1 = I_2 = I_3 = \frac{1.2}{2} = 0.4A$

 $\rm A_2 = I_2 + I_3 = 0.4 + 0.4 = 0.8 A$

(8)In the opposite figure three identical lamps connected with a battery of negligible internal resistance, what will happen to the brightness of lamp (B) when the switch (s) is closed?



a) increased b) increased 2 times c) decreased d) remains constant

The correct answer is remains constant

Because, the current intensity through lamp is unchanged

(9)In the circuit shown, the value of resistance (R) equals

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d)8Ω 0.5A R
                      b) 4Ω
a)2Ω
                                           b)6Ω
The correct answer is: 4\Omega
Because, I = \frac{v_B}{R+r} \rightarrow 0.5 = \frac{4}{\frac{16R}{16+R}+4+0.8} \rightarrow \frac{16R}{16+R} + 4.8 = 8
                                                                                        V_B = 4V, r = 0.8\Omega
3.2=\frac{16R}{16+R} \rightarrow R=4\Omega
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16Ω

4Ω

discharge.

V= 15 V V<sub>R</sub> = 5 x 1.46 = 7.3 V

And the current I3 = 1.46A

Terminal voltage of the battery 30 V:

V2 = V8 - 1r = 30 - (3.82 x 2) = 22.36 V

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If concentration of Si atoms is 4.42 × 10<sup>22</sup> atoms /cm<sup>3</sup> and silicon is doped with
 phosphorus in concentration of one phosphorus atom in one million Si atoms the
 concentration of free electrons and holes are .....
                                                       .....and ...
  (a) 3.2 \times 10^{11} cm^{-3}, 5.3 \times 10^{10}
                                             (b) 2.6× 10<sup>15</sup> cm<sup>-3</sup>, 3× 10<sup>10</sup>
  (c) 4.42× 10<sup>16</sup> cm<sup>-3</sup> ,1.303× 10<sup>10</sup>
                                           (d) 4.42× 10<sup>16</sup> cm<sup>-3</sup>,7× 10<sup>10</sup>
 The correct answer is 4.42 \times 10^{16} cm^{-3}, 1.303 \times 10^{10} cm^{-3}
 Because, N_D = \frac{4.42 \times 10^{22}}{10^{16}} = 4.42 \times 10^{16} \text{ cm}^{-3}
             (17) A diode has a resistance 200\Omega in forward bias connection.
(a)The current passing in it if a forward bias of +4v is applied on it is.....
    (1) 0.1A (2) 0.01A (3) 0.2A (d) 0.02A
(b) The current passing in it if a reverse bias of -4v is applied on it is..... A
    (1) -0.02 (2) -0.01 (3) 0.02 (4) Zero
  The correct answer is 0.002A, Zero
  Because, (a) for forward bias: I = \frac{v}{R} = \frac{4}{200} = 0.02A
               (b) for reverse bias the resistance of the diode
                      is very high \infty, so current I = 0.
   (18)In a transistor the ratio between the collector current and
    emitter current is \alpha_e = 0.99 and the base current has intensity 50 \mu A, then
       (a) TheCurrent amplification \beta_e =
             (1) 100
                                (2) 99
                                                   (3) 98
                                                                  (4) 97
       (b) Collector current I_{C} =
                                                   μA
            (1) 5050
                              (2) 5049
                                                                  (4) 1210
                                                  (3) 4950
   The correct answer is 99, 4950µA
   Because, (a) \beta_e = \frac{\alpha_e}{1 - \alpha_e} = \frac{0.99}{1 - 0.99} = \frac{0.99}{0.01} = 99
                (b) \beta_e = \frac{I_c}{I_b} \Longrightarrow I_c = \beta_e I_B = 99 \text{ x } 50 = 4950 \ \mu A
 (19)
An npn transistor works as a switch with V_{cc}=10 V and
R_c=1000~\Omega.
 the current of collector (I_c), in the following cases
 a) a +ve potential is applied on its base sufficient to make the transistor "on".
                               (2) 0.01 (3) 0.1
           (1) 0.001A
                                                                (4) Zero
 b) a -ve potential is applied on its base sufficient to make the transistor "off".
                               (2) 1
                                              (3) 2
          (1) Zero
                                                               (4) 3
   The correct answer is 0.01, Zero
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 $V_{cc} = V_{cE} + I_c R_c$ a) When transistor is on V<sub>CE</sub> is nearly = 0
 ∴ V<sub>CC</sub> = I<sub>c</sub>R<sub>c</sub> → I<sub>c</sub> = V<sub>CC</sub> = 10/1000 = 0.01 A
 b) If transistor is off I<sub>c</sub> = 0

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